## NSN 5962-01-339-5639

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View Online at https://aerobasegroup.com/nsn/5962-01-339-5639

View Online at https://derobasegroup.com/nsi//0302-01-003-0003
Overall Height:
Between 0.325 inches and 0.400 inches
Body Length:
1.060 inches
Body Width:
Between 0.220 inches and 0.310 inches
Body Height:
Between 0.130 inches and 0.185 inches
Maximum Power Dissipation Rating:
2.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Bipolar and monolithic and hermetically sealed and burn in
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:

10 input

**Case Outline Source And Designator:** 

D-8 mil-m-38510

**Current Rating Per Characteristic:** 

180.00 milliamperes supply

**Terminal Surface Treatment:** 

Solder

**Product Name:** 

Registered and-or gate array

**Voltage Rating And Type Per Characteristic:** 

-500.0 millivolts power source and 12.0 volts power source

**Time Rating Per Chacteristic:** 

30.00 nanoseconds propagation delay time, high to low level output and 30.00 nanoseconds propagation delay time, low to high level output

**Memory Device Type:** 

Programmed

**Test Data Document:** 

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

**Terminal Type And Quantity:** 

20 printed circuit

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	Life:

N/a

**Unit Of Measure:** 

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Demilitarization:

Yes - demil/mli

Fiig:

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